

FIG. 1

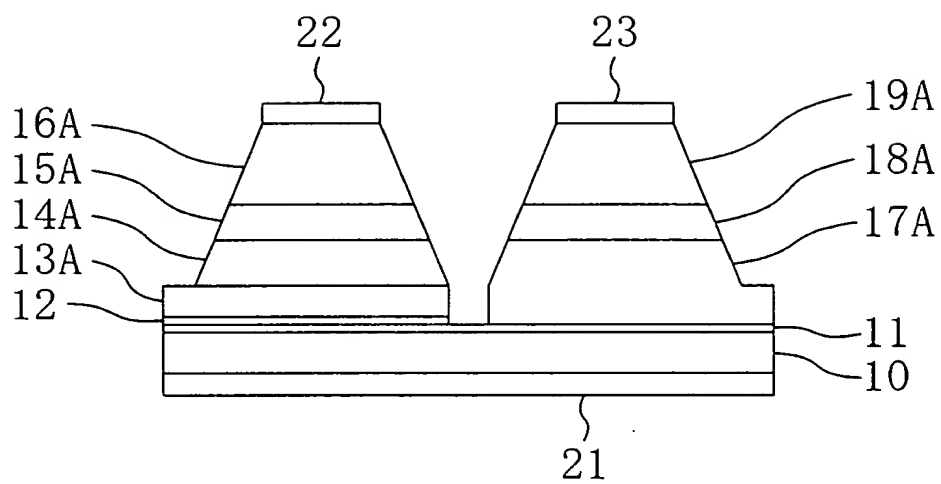
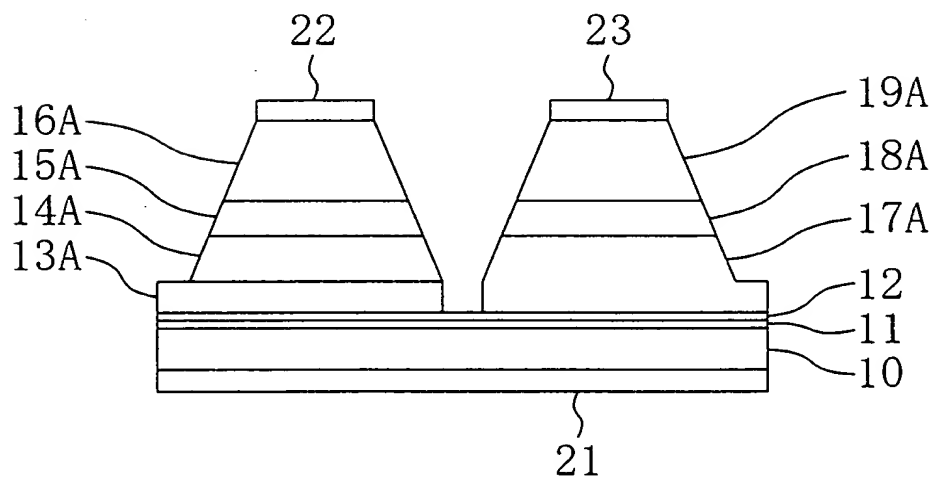
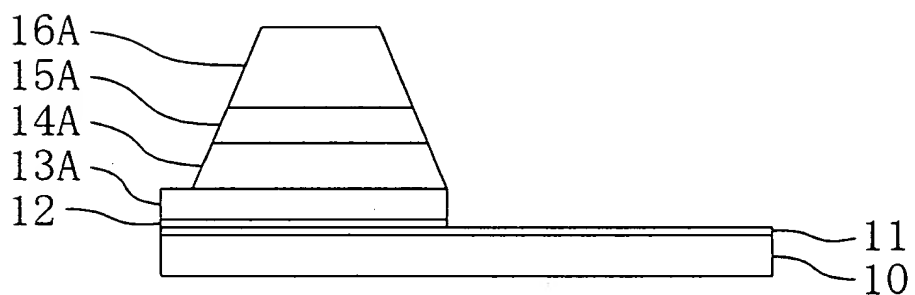


FIG. 2



A diagram showing a vertical stack of seven rectangular layers. The layers are labeled on the right side with numbers 10 through 16, from bottom to top. Layer 10 is the bottom-most layer, and layer 16 is the top-most layer. The layers are separated by thin lines, and the labels are connected to the layers by curved lines.



A cross-sectional view of a semiconductor device. The structure consists of a base layer 10, followed by a thin layer 11, and a thicker layer 12. On top of layer 12, there is a trapezoidal structure 13A. The top surface of this structure is labeled 14A. The side surface is labeled 15A. The top surface of the trapezoidal structure is labeled 16A. The right side of the structure is labeled 17, 18, and 19.

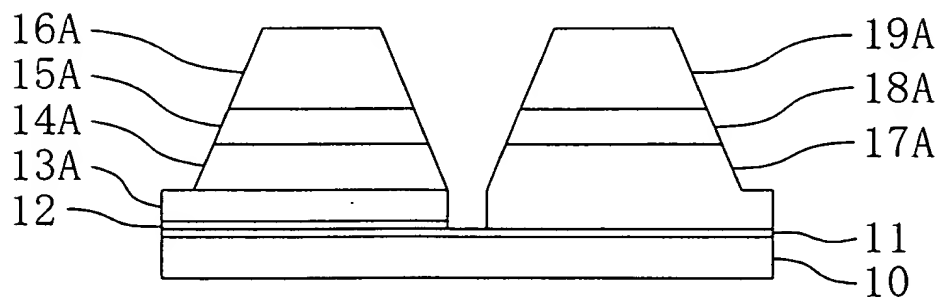


FIG. 3 (d)

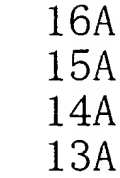
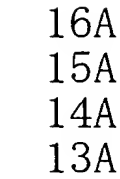
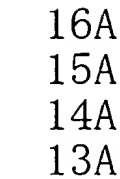
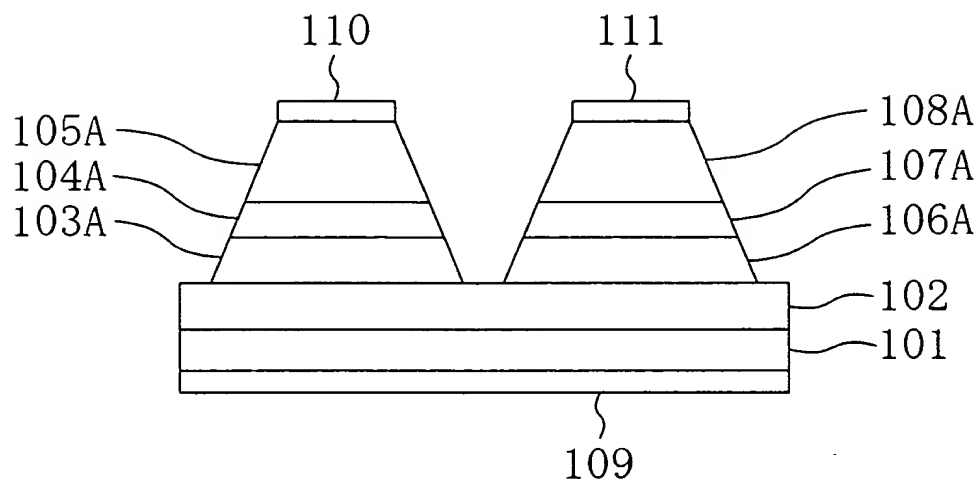
[illegible][illegible][illegible]

FIG. 5  
PRIOR ART



09747137 112000

00442600

FIG. 6(a)  
PRIOR ART

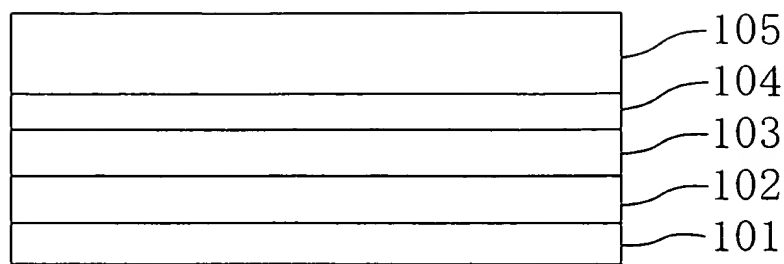


FIG. 6(b)  
PRIOR ART

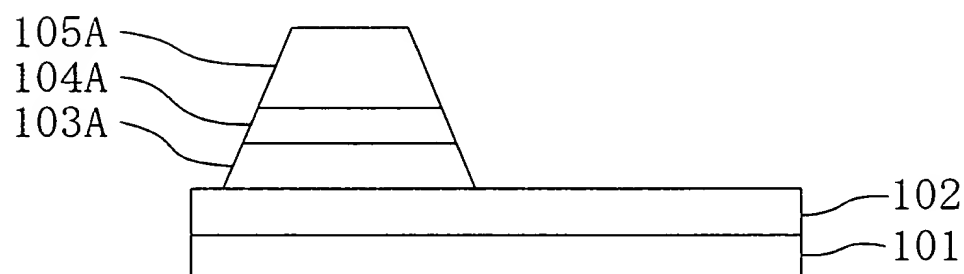


FIG. 6(c)  
PRIOR ART

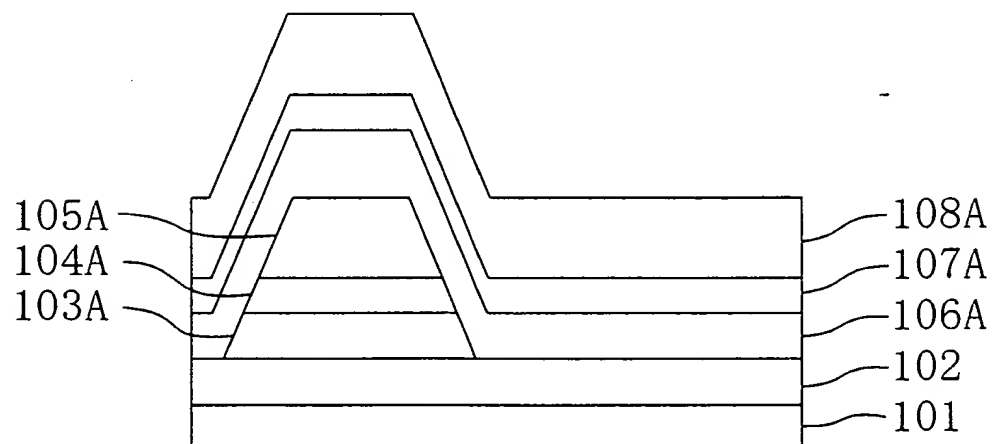


FIG. 6(d)  
PRIOR ART

